

TOSHIBA Field-Effect Transistor Silicon N Channel MOS Type

SSM6N43FU

○ High-Speed Switching Applications

- 1.5-V drive
- Low ON-resistance : $R_{DS(ON)} = 1.52 \Omega$ (max) (@ $V_{GS} = 1.5V$)
 : $R_{DS(ON)} = 1.14 \Omega$ (max) (@ $V_{GS} = 1.8V$)
 : $R_{DS(ON)} = 0.85 \Omega$ (max) (@ $V_{GS} = 2.5V$)
 : $R_{DS(ON)} = 0.66 \Omega$ (max) (@ $V_{GS} = 4.5V$)
 : $R_{DS(ON)} = 0.63 \Omega$ (max) (@ $V_{GS} = 5.0V$)

Absolute Maximum Ratings (Ta = 25°C) (Q1,Q2 Common)

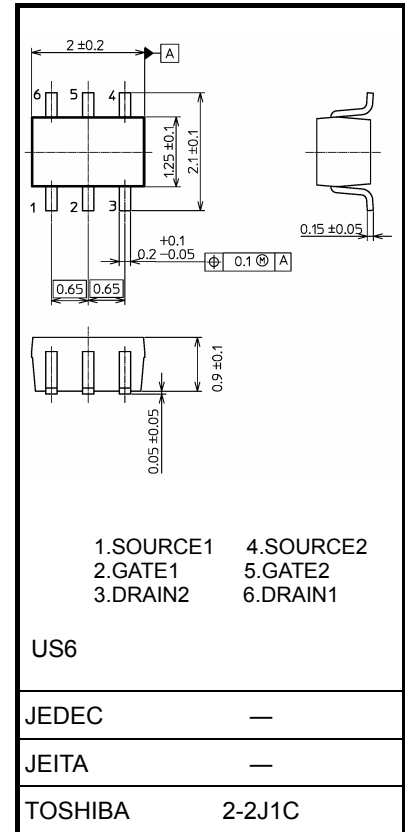
Characteristic	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	20	V
Gate-source voltage	V_{GSS}	± 10	V
Drain current	DC	I_D	500
	Pulse	I_{DP}	1000
Drain power dissipation	P_D (Note1)	200	mW
Channel temperature	T_{ch}	150	°C
Storage temperature range	T_{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

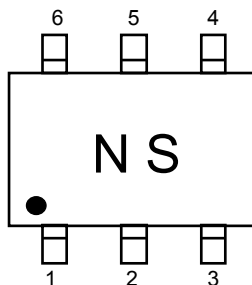
Note 1: Total rating

Unit: mm

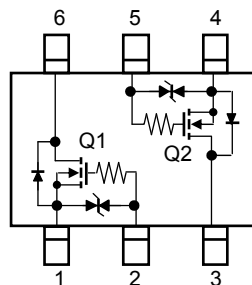


Weight: 6.8 mg (typ.)

Marking



Equivalent Circuit (top view)



Start of commercial production
2009-05

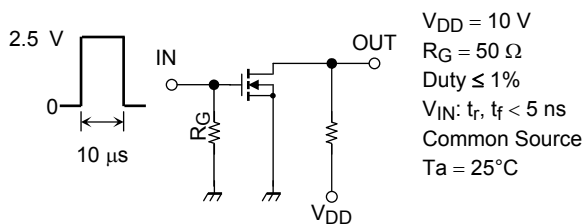
Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Drain-Source breakdown voltage	$V_{(BR)DSS}$	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}$	20	—	—	V
	$V_{(BR)DSX}$	$I_D = 1 \text{ mA}, V_{GS} = -10 \text{ V}$	12	—	—	
Drain cut-off current	I_{DSS}	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}$	—	—	1	μA
Gate leakage current	I_{GSS}	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$	—	—	± 1	μA
Gate threshold voltage	V_{th}	$V_{DS} = 3 \text{ V}, I_D = 1 \text{ mA}$	0.35	—	1.0	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 3 \text{ V}, I_D = 200 \text{ mA}$ (Note2)	420	840	—	mS
Drain-Source ON resistance	$R_{DS(ON)}$	$I_D = 200 \text{ mA}, V_{GS} = 5.0 \text{ V}$ (Note2)	—	0.46	0.63	Ω
		$I_D = 200 \text{ mA}, V_{GS} = 4.5 \text{ V}$ (Note2)	—	0.51	0.66	
		$I_D = 200 \text{ mA}, V_{GS} = 2.5 \text{ V}$ (Note2)	—	0.66	0.85	
		$I_D = 100 \text{ mA}, V_{GS} = 1.8 \text{ V}$ (Note2)	—	0.81	1.14	
		$I_D = 50 \text{ mA}, V_{GS} = 1.5 \text{ V}$ (Note2)	—	0.95	1.52	
Input capacitance	C_{iss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	—	46	—	pF
Output capacitance	C_{oss}		—	10.8	—	
Reverse transfer capacitance	C_{rss}		—	7.3	—	
Total Gate Charge	Q_g	$V_{DD} = 10 \text{ V}, I_D = 0.5 \text{ A}$ $V_{GS} = 4.0 \text{ V}$	—	1.23	—	nC
Gate-Source Charge	Q_{gs}		—	0.60	—	
Gate-Drain Charge	Q_{gd}		—	0.63	—	
Switching time	Turn-on time	t_{on}	$V_{DD} = 10 \text{ V}, I_D = 200 \text{ mA}$ $V_{GS} = 0 \text{ to } 2.5 \text{ V}, R_G = 50 \Omega$	—	30	ns
	Turn-off time	t_{off}		—	75	
Drain-source forward voltage	V_{DSF}	$I_D = -0.5 \text{ A}, V_{GS} = 0 \text{ V}$ (Note2)	—	-0.88	-1.2	V

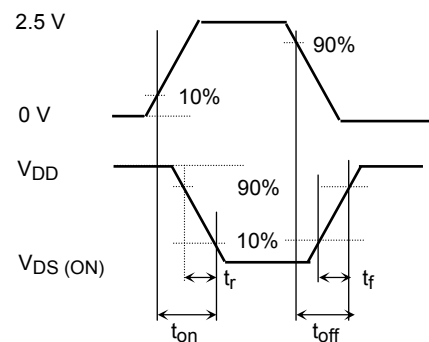
Note2: Pulse test

Switching Time Test Circuit

(a) Test Circuit



(b) V_{IN}



(c) V_{OUT}

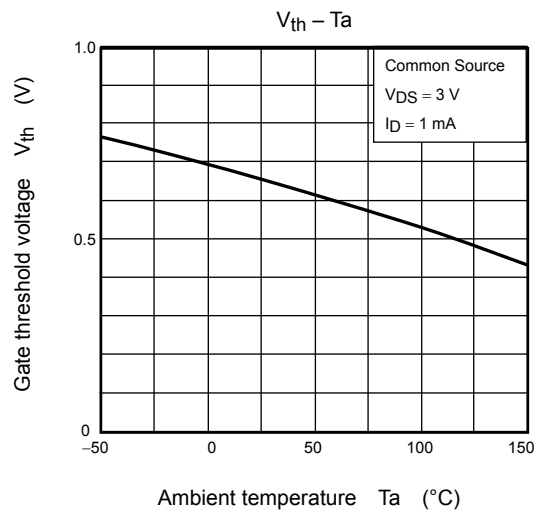
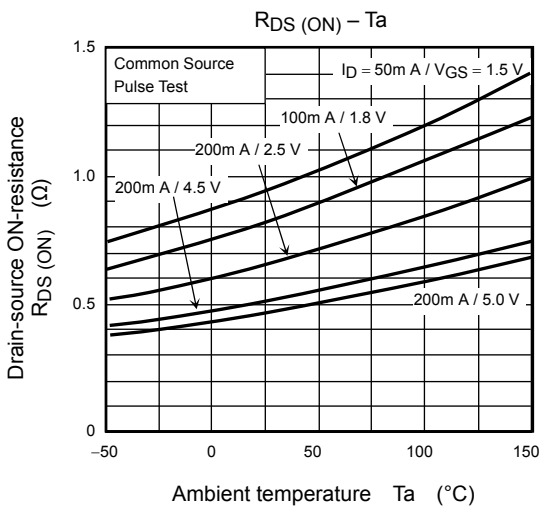
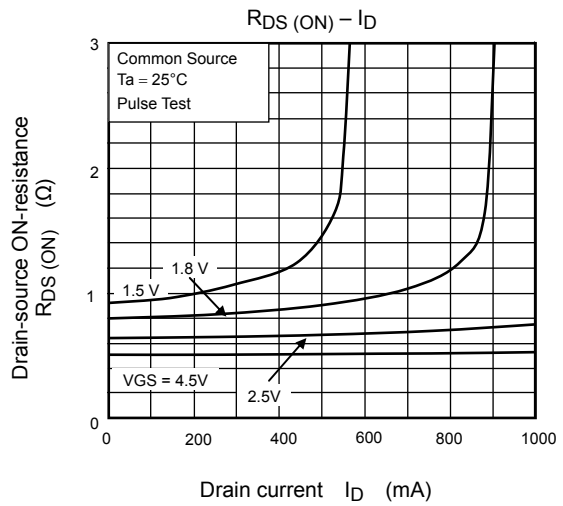
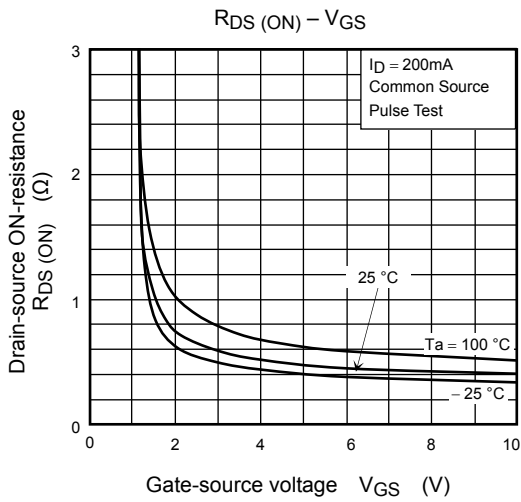
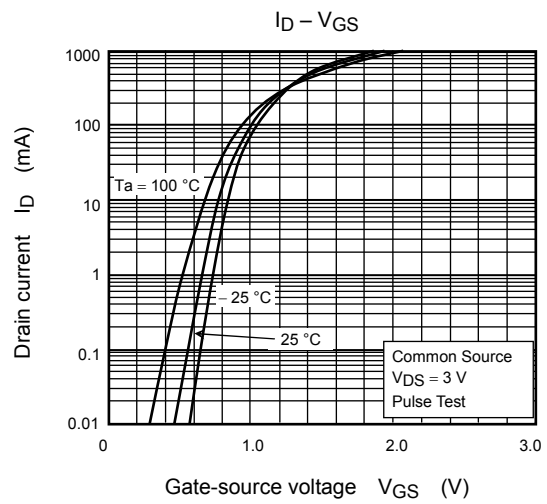
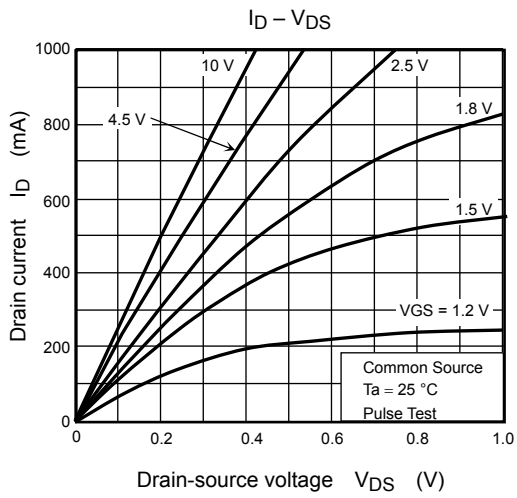
Usage Considerations

Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to be below (1 mA for the SSM6N43FU). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$. Take this into consideration when using the device.

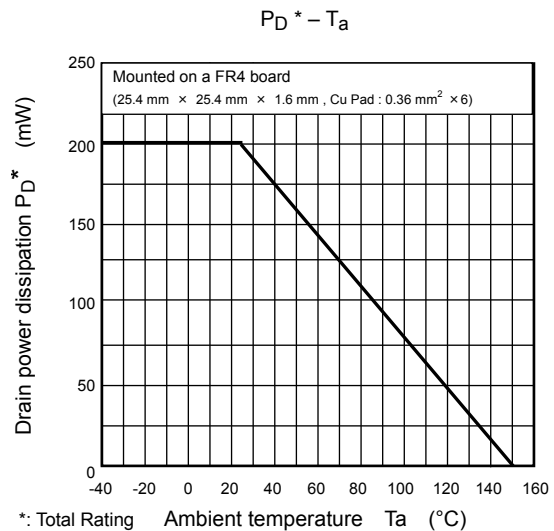
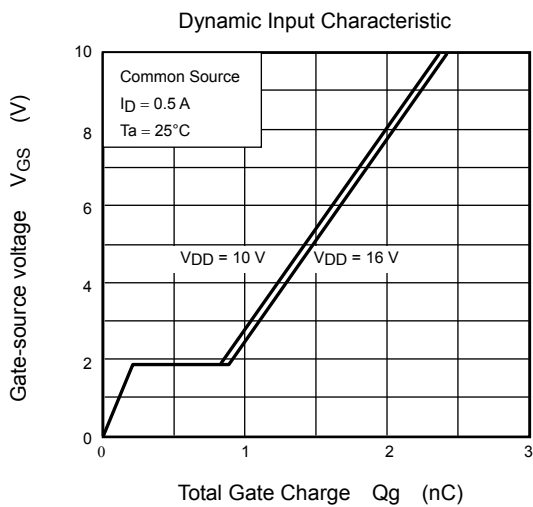
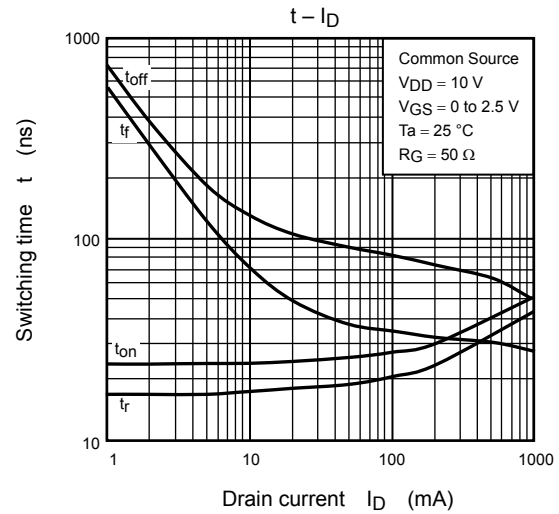
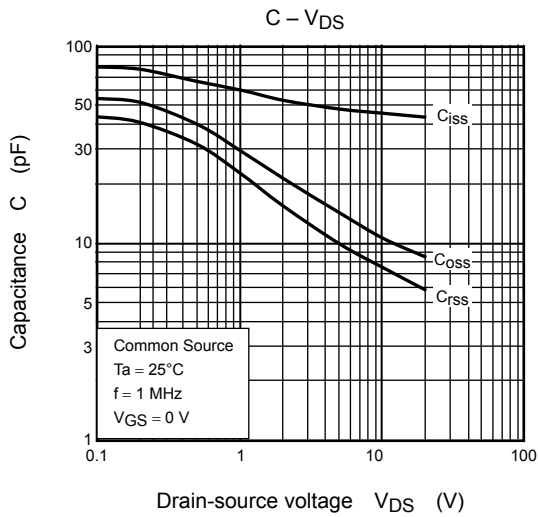
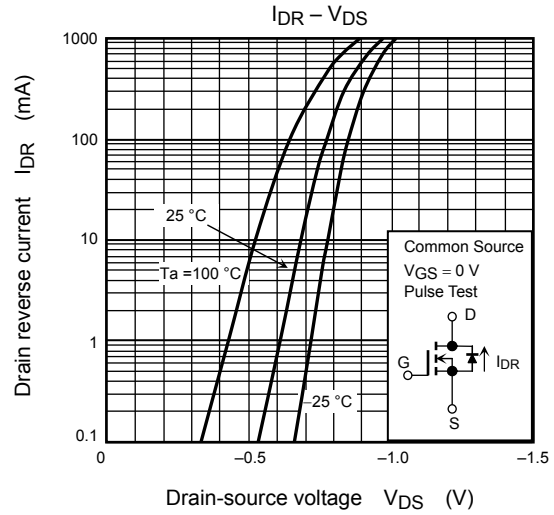
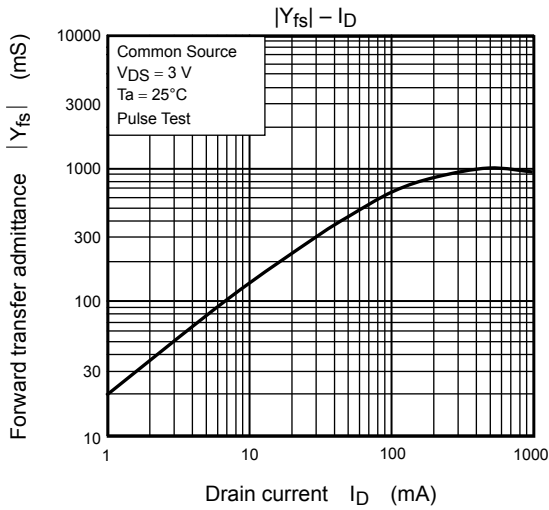
Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

(Q1, Q2 Common)



(Q1, Q2 Common)



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